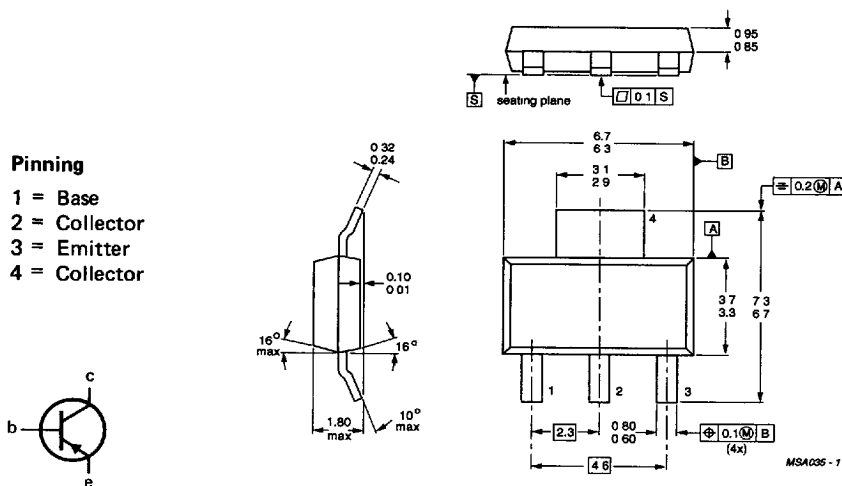


PNP medium power transistors in a microminiature SMD envelope (SOT-223). Designed primarily for high-speed switching and driver applications.

Collector-base voltage (open emitter)		$-V_{CBO}$	max.	60 V
Collector-emitter voltage (open base)	PZT2907	$-V_{CEO}$	max.	40 V
	PZT2907A	$-V_{CEO}$	max.	60 V
Collector current (DC)		$-I_C$	max.	600 mA
Total power dissipation up to $T_{amb} = 25\text{ }^{\circ}\text{C}$		P_{tot}	max.	1,5 W
Junction temperature		T_j	max.	150 $^{\circ}\text{C}$
DC current gain at $T_j = 25\text{ }^{\circ}\text{C}$ $-I_C = 150\text{ mA}; -V_{CE} = 10\text{ V}$		h_{FE}		100 to 300
Transition frequency at $f = 100\text{ MHz}$ $-I_C = 50\text{ mA}; -V_{CE} = 20\text{ V}; T_j = 25\text{ }^{\circ}\text{C}$		f_T	min.	200 MHz
Storage time $-I_{Con} = 150\text{ mA}; -I_{Bon} = I_{Boff} = 15\text{ mA}$		t_s	max.	80 ns

Dimensions in mm

Fig. 1 SOT-223



RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Collector-base voltage (open emitter)		$-V_{CBO}$	max.	60 V
Collector-emitter voltage (open base)	PZT2907	$-V_{CEO}$	max.	40 V
	PZT2907A	$-V_{CEO}$	max.	60 V
Emitter-base voltage (open collector)		$-V_{EBO}$	max.	5 V
Collector current (DC)		$-I_C$	max.	600 mA
Total power dissipation up to $T_{amb} = 25\text{ }^{\circ}\text{C}$		P_{tot}	max.	1,5 W
Storage temperature range		T_{stg}	-65 to +150	$^{\circ}\text{C}$
Junction temperature		T_j	max.	150 $^{\circ}\text{C}$

THERMAL RESISTANCE

From junction to ambient*	$R_{th\ j-a}$	=	83,3 K/W
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* Device mounted on an epoxy printed-circuit board 40 mm x 40 mm x 1,5 mm;
mounting pad for the collector lead min. 6 cm².

CHARACTERISTICS

 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Collector cut-off current

 $I_E = 0; -V_{CB} = 50\text{ V}$ $-I_{CBO} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 20 & 10 \end{array} \text{ nA}$ $I_E = 0; -V_{CB} = 50\text{ V}; T_{amb} = 150\text{ }^{\circ}\text{C}$ $-I_{CBO} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 20 & 10 \end{array} \mu\text{A}$ $+V_{BE} = 0,5\text{ V}; -V_{CE} = 30\text{ V}$ $-I_{CEX} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 50 & 50 \end{array} \text{ nA}$

Base current

 $+V_{BE} = 0,5\text{ V}; -V_{CE} = 30\text{ V}$ $I_{BEX} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 50 & 50 \end{array} \text{ nA}$

Collector-base breakdown voltage

open emitter; $-I_C = 10\text{ }\mu\text{A}$ $-V_{(BR)CBO} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 60 & 60 \end{array} \text{ V}$

Collector-emitter breakdown voltage*

open base; $-I_C = 10\text{ mA}$ $-V_{(BR)CEO} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 40 & 60 \end{array} \text{ V}$

Emitter-base breakdown voltage

open collector; $-I_E = 10\text{ }\mu\text{A}$ $-V_{(BR)EBO} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 5 & 5 \end{array} \text{ V}$

Saturation voltages*

 $-I_C = 150\text{ mA}; -I_B = 15\text{ mA}$ $-V_{CEsat} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 0,4 & 0,4 \end{array} \text{ V}$ $-V_{BEsat} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 1,3 & 1,3 \end{array} \text{ V}$ $-I_C = 500\text{ mA}; -I_B = 50\text{ mA}$ $-V_{CEsat} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 1,6 & 1,6 \end{array} \text{ V}$ $-V_{BEsat} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 2,6 & 2,6 \end{array} \text{ V}$

DC current gain

 $-I_C = 0,1\text{ mA}; -V_{CE} = 10\text{ V}$ $h_{FE} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 35 & 75 \end{array}$ $-I_C = 1\text{ mA}; -V_{CE} = 10\text{ V}$ $h_{FE} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 50 & 100 \end{array}$ $-I_C = 10\text{ mA}; -V_{CE} = 10\text{ V}$ $h_{FE} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 75 & 100 \end{array}$ $-I_C = 150\text{ mA}; -V_{CE} = 10\text{ V}^*$ $h_{FE} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 100 & 100 \end{array}$ $h_{FE} < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 300 & 300 \end{array}$ $-I_C = 500\text{ mA}; -V_{CE} = 10\text{ V}^*$ $h_{FE} > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 30 & 50 \end{array}$ Collector capacitance at $f = 100\text{ kHz}$ $I_E = I_C = 0; -V_{CB} = 10\text{ V}$ $C_c < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 8 & \end{array} \text{ pF}$ Emitter capacitance at $f = 100\text{ kHz}$ $I_C = I_E = 0; -V_{EB} = 2\text{ V}$ $C_e < \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 30 & \end{array} \text{ pF}$ Transition frequency at $f = 100\text{ MHz}$ $-I_C = 50\text{ mA}; -V_{CE} = 20\text{ V}^*$ $f_T > \begin{array}{c|c} \text{PZT2907} & \text{PZT2907A} \\ \hline 200 & \end{array} \text{ MHz}$ * Measured under pulse conditions to avoid excessive dissipation: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0,02$.

Turn-on time (see Fig. 2)

when switched to $-I_{Con} = 150 \text{ mA}$; $-I_{Bon} = 15 \text{ mA}$

delay time

rise time

turn-on time

$$t_d < 10 \text{ ns}$$

$$t_r < 40 \text{ ns}$$

$$t_{on} < 45 \text{ ns}$$

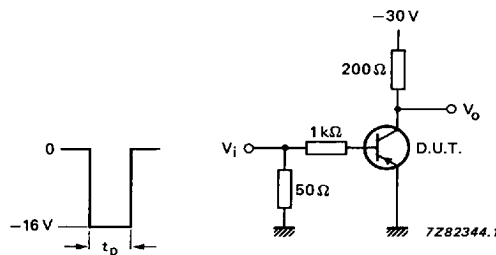


Fig. 2 Input waveform and test circuit for determining delay, rise and turn-on time.

Turn-off time (see Fig. 3)

when switched from $-I_{Con} = 150 \text{ mA}$; $-I_{Bon} = 15 \text{ mA}$

to cut-off with $+I_{Boff} = 15 \text{ mA}$

storage time

fall time

turn-off time

$$t_s < 80 \text{ ns}$$

$$t_f < 30 \text{ ns}$$

$$t_{off} < 100 \text{ ns}$$

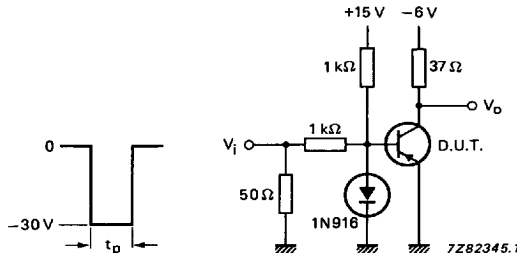


Fig. 3 Input waveform and test circuit for determining storage, fall and turn-off time.

Pulse generator (see Figs 2 and 3)

frequency $f = 150 \text{ Hz}$

pulse duration $t_p = 200 \text{ ns}$

rise time $t_r \leq 2 \text{ ns}$

output impedance $Z_o = 50 \Omega$

Oscilloscope (see Figs 2 and 3)

rise time $t_r \leq 5 \text{ ns}$

input impedance $Z_i \leq 10 \text{ M}\Omega$